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View Online at https://aerobasegroup.com/nsn/5961-01-624-8012 **Inclosure Material:** Plastic **Overall Length:** 5.44 millimeters **Terminal Length:** 2.03 millimeters **Overall Height:** 3.56 millimeters **Overall Width:** 2.20 millimeters **Function For Which Designed:** Zener diode and transient suppressor **End Application:** B-1 bomber **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method: Terminal Features Provided:** Electrostatic sensitive and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 5.00 microamperes reverse current, dc **Power Rating Per Characteristic:** 600.0 watts peak pulse output power **Capacitance Rating In Picofarads: Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Product Name:** Semiconductor device zener diode transient voltage suppressor **Terminal Type And Quantity:** 2 pin Shelf Life: N/a

Unit Of Measure:

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Demilitarization:

No

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